

L Number	Hits	Search Text	DB	Time stamp
34	456	memory adj write near buffer	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 16:11
35	1	non\$1volatile with stop adj bit	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 16:13
36	61	non\$1volatile with data adj transfer with (buffer or latch)	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 16:50
37	16	data adj transfer with (completion or end) with stop adj bit	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:32
38	2	(external or exterior) near data adj transfer with non\$1volatile	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:34
39	3504	program\$5 near non\$1volatile adj memory	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:35
40	2988	program\$5 adj non\$1volatile adj memory	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:35
41	726	programming adj non\$1volatile adj memory	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:35
42	12	programming adj non\$1volatile adj memory with buffer	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:37
43	0	variable adj write adj buffer adj width	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:37
44	6	write adj buffer adj width	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:38
45	122	peripheral adj buffer	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:55
46	3593	non\$1volatile adj memory near program\$5	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 17:56
47	26	non\$1volatile adj memory near program\$5 with control adj system	IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PPGPUB; EPO; JPO; DERWENT;	2004/08/30 18:02

48	65	non\$1volatile adj memory near program\$5 with high adj voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/08/30 18:04
49	7	non\$1volatile adj memory near program\$5 with serial adj data	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/08/30 18:04